

# SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

# MCH3106 — PNP Epitaxial Planar Silicon Transistor DC / DC Converter Applications

### **Applications**

· Relay drivers, lamp drivers, motor drivers, flash

### **Features**

- · Adoption of MBIT processes
- · Low collector-to-emitter saturation voltage
- Litter and it and a second control saturation voltage
- · Ultrasmall package facilitates miniaturization in end products (mounting height: 0.85mm)
- · High allowable power dissipation

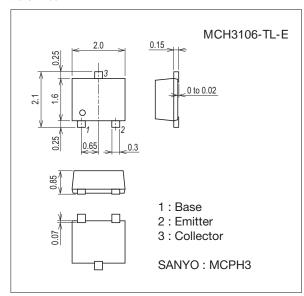
### **Specifications**

### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-15	V
Collector-to-Emitter Voltage	VCEO		-12	V
Emitter-to-Base Voltage	VEBO		-5	V
Collector Current	IC		-3	Α
Collector Current (Pulse)	ICP		-5	Α
Base Current	IB		-600	mA
Collector Dissipation	PC	When mounted on ceramic substrate (600mm <sup>2</sup> ×0.8mm)	0.9	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### **Package Dimensions**

unit : mm (typ) 7019A-004



### **Product & Package Information**

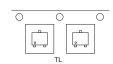
• Package : MCPH3

JEITA, JEDEC : SC-70, SOT-323
 Minimum Packing Quantity : 3,000 pcs./reel

### Packing Type: TL

· Large current capacity

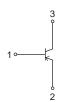
· High-speed switching



## Marking



### **Electrical Connection**

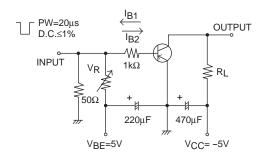


### MCH3106

### **Electrical Characteristics** at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
Farameter	Symbol	Conditions	min	typ	max	Office	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =-12V, I <sub>E</sub> =0A			-0.1	μΑ	
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =-4V, I <sub>C</sub> =0A			-0.1	μΑ	
DC Current Gain	hFE	V <sub>CE</sub> =-2V, I <sub>C</sub> =-500mA	200		560		
Gain-Bandwidth Product	f⊤	V <sub>CE</sub> =-2V, I <sub>C</sub> =-500mA		280		MHz	
Output Capacitance	Cob	V <sub>CB</sub> =-10V, f=1MHz		36		pF	
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =-1.5A, I <sub>B</sub> =-30mA		-110	-165	mV	
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> =-1.5A, I <sub>B</sub> =-30mA		-0.85	-1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =-10μA, I <sub>E</sub> =0A	-15			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=-1mA, RBE=∞	-12			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=-10μA, IC=0A	-5			V	
Turn-On Time	ton			30		ns	
Storage Time	t <sub>stg</sub>	See specified Test Circuit.		90		ns	
Fall Time	tf			10		ns	

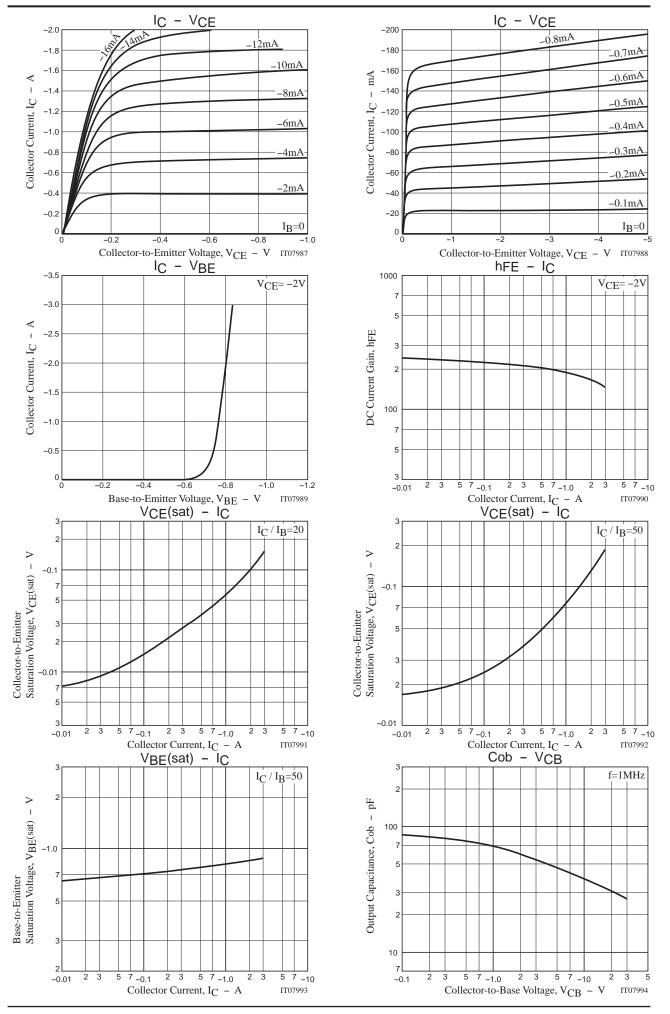
### **Switching Time Test Circuit**



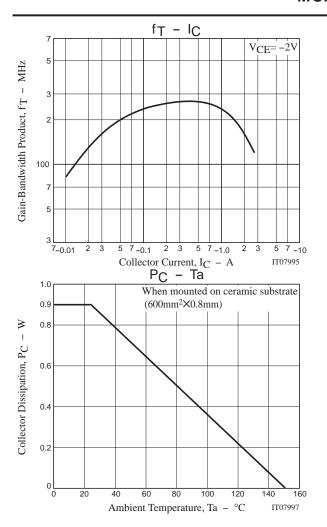
 $I_{C}=20I_{B2}=-20I_{B1}=-1.5A$ 

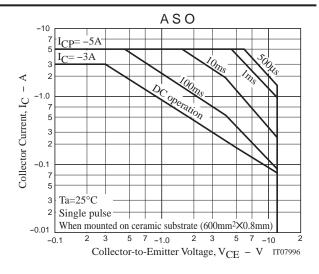
### **Ordering Information**

Device	Package	Shipping	memo		
MCH3106-TL-E	MCPH3	3,000pcs./reel	Pb Free		



### MCH3106



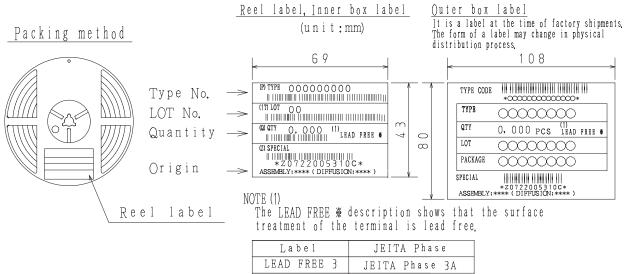


### **Taping Specification**

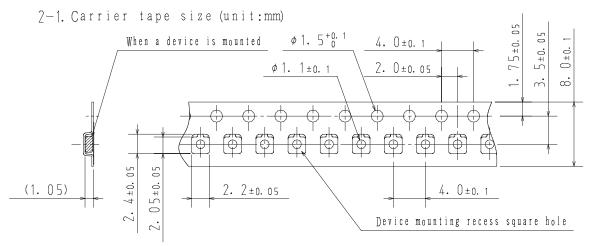
### MCH3106-TL-E

### 1. Packing Format

Package Name	Carrier Tape	Maximun Number of devices contained (pcs)			Packing format		
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
мсрн3	мсрн3	3,000	15, 000	90,000	5 reels contained	6 inner boxes contained	
					Dimensions:mm (external)	Dimensions:mm (external)	
					183×72×185	440×195×210	

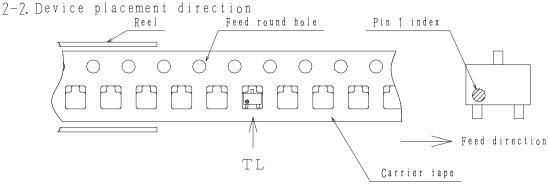


### 2. Taping configuration



LEAD FREE 4

JEITA Phase 3



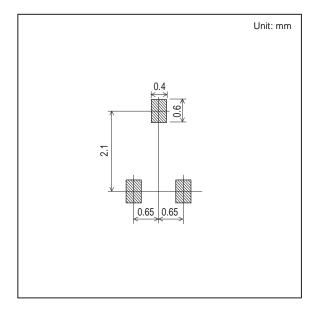
Those with pin 1 index on the feed hole side·····TL

### **Outline Drawing**

MCH3106-TL-E

# Mass (g) Unit 0.007 For reference mm 2.0+0.05 2.0+0.05 2.0+0.05 2.0+0.05 2.0+0.05 2.0+0.05 3.0+0.05 2.0+0.05 3.0+0.05 4.1:Let indication

### **Land Pattern Example**



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